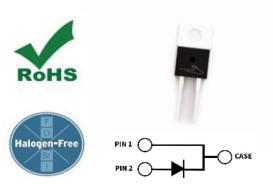


6th Generation 650 V, 8 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher e iciency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.



Package Types: TO-220-2 Marking: C6D08065A

Features

- Low Forward Voltage (V_F) Drop with Positive Temperature Coe icient
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior

Applications

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters

Maximum Ratings ($T_C = 25^{\circ}C$ Unless Otherwise Specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	V _{RRM}	650				
DC Blocking Voltage	V _{DC}	650	V			
		30		T _J = 25 °C		
Continuous Forward Current	l _F	16	А	T _J = 125 °C	Fig. 3	
		8		T _J = 155 °C		
Repetitive Peak Forward Surge Current	I _{FRM}	37		$T_{\rm C} = 25$ °C, $t_{\rm p} = 10$ ms, Half Sine Wave		
		22		$T_{\rm C} = 110 {\rm ^{\circ}C}$, $t_{\rm p} = 10 {\rm ms}$, Half Sine Wave		
Non-Repetitive Forward Surge Current	I _{FSM}	69		$T_{\rm C} = 25$ °C, $t_{\rm p} = 10$ ms, Half Sine Wave		
		63		T _C = 110 °C,t _p = 10 ms, Half Sine Wave	Fig. 8	
Non-Repetitive Peak Forward Surge Current	l F,Max	860		$T_{\rm C} = 25 {\rm ^{\circ}C}, t_{\rm p} = 10 \mu \rm s, Pulse$		
		790		T _C = 110°C, t _p = 10 μs, Pulse		
Power Dissipation	P _{tot}	92.6	W	T _J = 25 °C	Fig. 4	
		40.1		T _J = 110 °C		

Electrical Characteristics

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes
Forward Voltage	.,	1.27	1.50	V	$I_F = 8 \text{ A}, T_j = 25 \text{ °C}$	F .
	V _F	1.37	1.60		I _F = 8 A, T _j = 175 °C	Fig. 1
Reverse Current		2	40	μА	$V_R = 650 \text{ V}, T_j = 25 \text{ °C}$	- Fa. 0
	I _R	15	160		$V_R = 650 \text{ V}, T_j = 175 \text{ °C}$	Fig. 2
Total Capacitive Charge	Q_{c}	29		nC	$V_{R} = 400 \text{ V}, T_{j} = 25 ^{\circ}\text{C}$	Fig. 5
		518			$V_R = 0 \text{ V}, T_j$	
Total Capacitance	С			pF		

Typical Performance

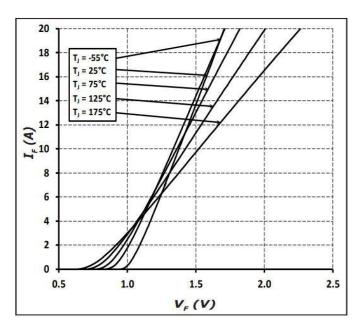


Figure 1Forward Characteristics

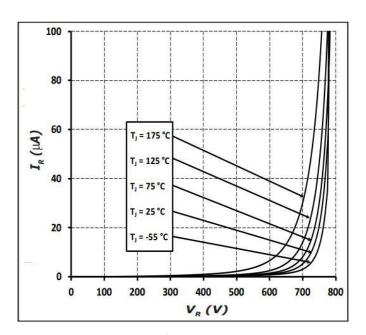


Figure 2Reverse Characteristics

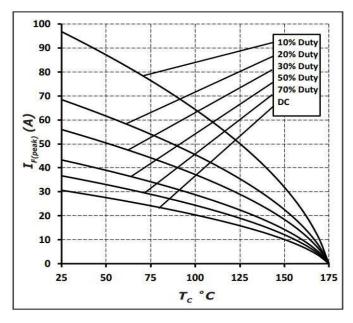


Figure 3Current Derating

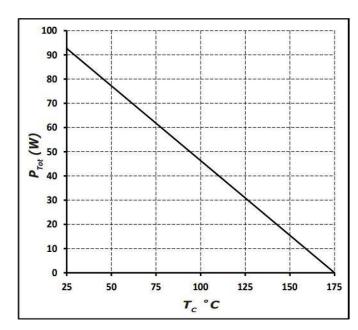
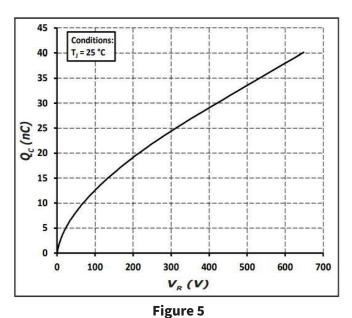


Figure 4Power Derating



Total Capacitance vs. Reverse Voltage

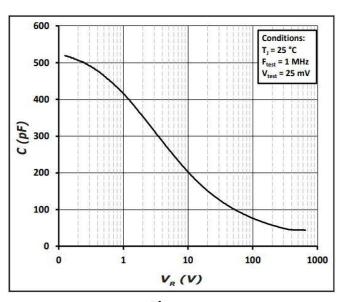


Figure 6Capacitace vs. Reverse Voltage

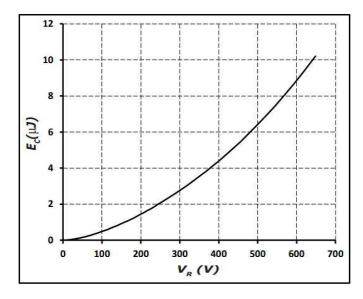


Figure 7
Capacitance Stored Energy

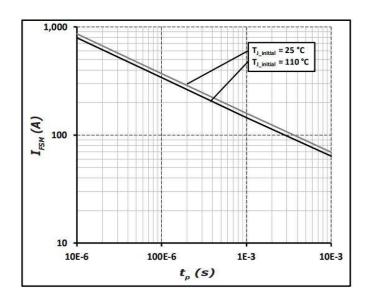


Figure 8Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)

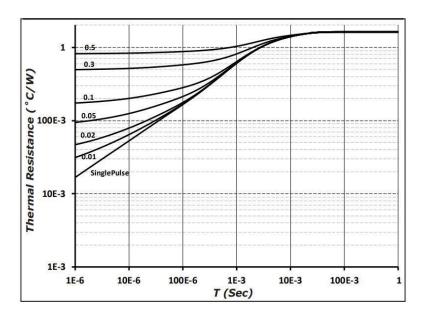
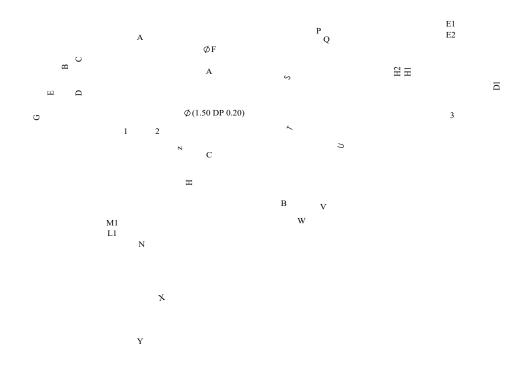


Figure 9
Transient Thermal Impedance

Package Dimensions & Pin-Out

Package: TO-220-2



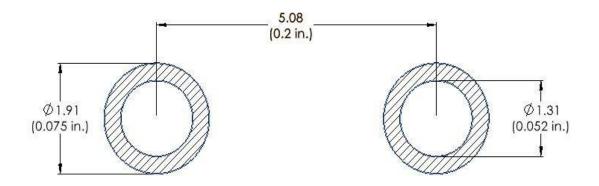
NOTE

- $\begin{array}{l} {\rm 1.\;ALL\;METAL\;SURFACES\;ARE\;TIN\;PLATED\;(MATTE),} \\ {\rm EXCEPT\;AREA\;OF\;CUT.} \end{array}$
- $\begin{tabular}{ll} 2. & DIMENSIONING \& TOLERANCING CONFORM TO \\ & ASME Y14.5M-1994. \end{tabular}$
- 3. ALL DIMENSIONS ARE LISTED IN MILLIMETERS. ANGLES ARE IN DEGREES.
- 4. PACKAGE BURR FLASH SIZE (0.5 mm) IS NOT INCLUDED IN THE DIMENSIONS



Recommended Solder Pad Layout

Primary dimensions shown in mm. Learn more about recommended soldering profiles in this application note.



Product Ordering Information

Order Number	Packing Type
C6D08065A	Tube

Learn more about power device packing & shipment information in this application note.

Revision History

Document Version	Date of Release	Description of Changes
0	April-2019	Initial Release
1	March-2023	Update Package Drawing Update Landing Pad

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